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EFFECT OF PARAMAGNETIC Co₆₇Cr₃₃ UNDERLAYER ON CRYSTALLOGRAPHIC AND MAGNETIC CHARACTERISTICS OF Co-Cr-Ta LAYERS IN PERPENDICULAR MAGNETIC RECORDING MEDIA

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ABSTRACT

The bi-layered films composed of Co-Cr-Ta layers and paramagnetic Co₆₇Cr₃₃ underlayer were deposited by sputtering Facing Targets Sputtering (FTS). The effects of Co₆₇Cr₃₃ underlayer on the crystallographic and magnetic characteristics of the Co-Cr-Ta layer deposited on the underlayer was investigated. The diffraction intensity $I_{p(002)}$ of Co-Cr-Ta layers on the Co₆₇Cr₃₃ layer was stronger than that of single layer and Co-Cr-Ta/Ti double layer. Therefore, the crystallinity of Co-Cr-Ta layer was improved by the Co₆₇Cr₃₃ underlayer rather than Ti ones. However, the coercivity $H_{c\perp}$ of Co-Cr-Ta layers deposited on Co₆₇Cr₃₃ underlayer was as low as 250 Oe even at substrate temperature of 220°C. This $H_{c\perp}$ decrease seems to be attributed to the effect of the Co₆₇Cr₃₃ underlayer as well as interval time between deposition of the underlayer and the Co-Cr-Ta layer.

INTRODUCTION

The good crystallinity and appropriate coercivity of Co-Cr films are the essential factors to attain high density perpendicular magnetic recording. In general, those of the Co-Cr films have been improved by using underlayers such as Ti, Ge, etc.^[1] Moreover, the (111) plane orientation of fcc crystallites in the Ni-Fe back-layer have been improved using the paramagnetic Co₆₇Cr₃₃ underlayer proposed in previous work.^[2] These results suggest that the Co₆₇Cr₃₃ underlayer can improve the crystallinity of Co-Cr recording layer. In this study, the effects of the para-

magnetic Co₆₇Cr₃₃ underlayer on the crystallographic and magnetic characteristics of Co-Cr-Ta layers were investigated.

EXPERIMENTS

The Co₈₀Cr₁₇Ta₃ single layer, Co₈₀Cr₁₇Ta₃/Ti and Co₈₀Cr₁₇Ta₃/Co₆₇Cr₃₃ bi-layers structure were deposited on glass slide substrates using Facing Targets Sputtering (FTS) apparatus. The Ar gas pressure P_{AR} during deposition of the Co-Cr-Ta layers was fixed at 0.3 mTorr. P_{AR} during deposition of paramagnetic Co₆₇Cr₃₃ and Ti underlayers were also fixed at 0.3 mTorr. The thicknesses of Co-Cr-Ta layers

and underlayers were 20nm and 20nm, respectively. The substrate temperature T_s during deposition of the Co-Cr-Ta layers were varied in the range from Room Temperature(R.T.) to 270°C. The substrate temperature during deposition of the $\text{Co}_{67}\text{Cr}_{33}$ layer T_{us} were R.T. or 220°C. Ti underlayer were deposited at T_{us} of 220°C. In addition to these films, the 20nm-thick Co-Cr-Ta layer was deposited which includes 20nm-thick initial growth layer prepared in mixture gas of N_2 and Ar at T_s of 220°C. Here, this initial growth layer was defined as Co-Cr-Ta : N layer.

The total pressure $P_{\text{N}_2} + P_{\text{Ar}}$ and N_2 partial pressure P_{N_2} were 1 mTorr and 0.1 mTorr, respectively. The Co-Cr-Ta layer was deposited at P_{Ar} of 1 mTorr and T_s of 220°C. The crystallographic characteristics were evaluated by X-ray diffractometry(XRD). The magnetic characteristics were determined using Vibrating Sample Magnetometer(VSM) and Kerr hysteresis tracer.

RESULTS AND DISCUSSION

Fig. 1 shows the substrate temperature T_s dependences of X-ray diffraction intensity $I_{\text{p}(002)}$ of Co(002) plane on substrate temperature T_s for Co-Cr-Ta single layers, Co-Cr-Ta/Ti and Co-Cr-Ta/ $\text{Co}_{67}\text{Cr}_{33}$ double layer, respectively. $I_{\text{p}(002)}$ of the Co-Cr-Ta layer deposited on the $\text{Co}_{67}\text{Cr}_{33}$ underlayer at T_{us} of R.T. was stronger than those of the Co-Cr-Ta single layer and Co-Cr-Ta/Ti double layer at any T_s . The crystallinity of the Co-Cr-Ta layer was improved, since the Co-Cr-Ta layer grew homo-epitaxially on the $\text{Co}_{67}\text{Cr}_{33}$ layers and possessed thinner initial growth

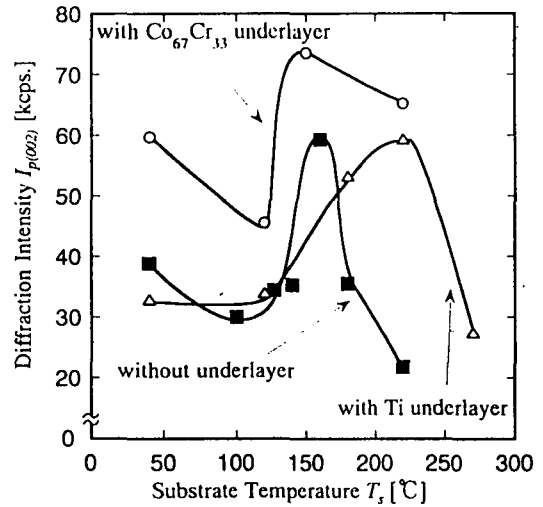


Fig. 1 T_s dependences of X-ray diffraction intensity $I_{\text{p}(002)}$ of single layer and double layers.

layer, which exhibited worse c-axis orientation and lower perpendicular coercivity.^[3] On the other hand, $I_{\text{p}(002)}$ of Co-Cr-Ta layers on the Ti underlayers were slightly stronger than that of single layer deposited at T_s between 180 and 220°C.

The effect of the $\text{Co}_{67}\text{Cr}_{33}$ underlayer on the magnetic characteristics was investigated. Fig. 2 shows the T_s dependences of $H_{c\perp}$ of single layers and double layers. $H_{c\perp}$ of the single layers, increased with increase of T_s in the range above 150°C and took a high value of about 1500 Oe at T_s of 220°C. $H_{c\perp}$ of the Co-Cr-Ta/Ti double layer also increased with increase of T_2 in the range above T_2 of 180°C. It seems that the change of the threshold value of coercivity is attributed to the interval time between the deposition of Co-Cr-Ta and Ti layer. The impurity, such as O_2 , N_2 and H_2O , seems to be adhered to the surface of the Ti underlayer during this interval. So, the impurity seems to diffuse in the thickness direction during deposition of the Co-Cr-Ta

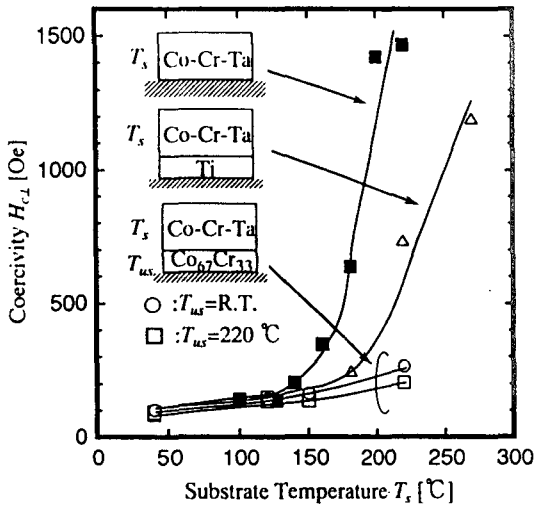


Fig. 2 T_s dependences of perpendicular coercivity $H_{c\perp}$ in single layer and double layer.

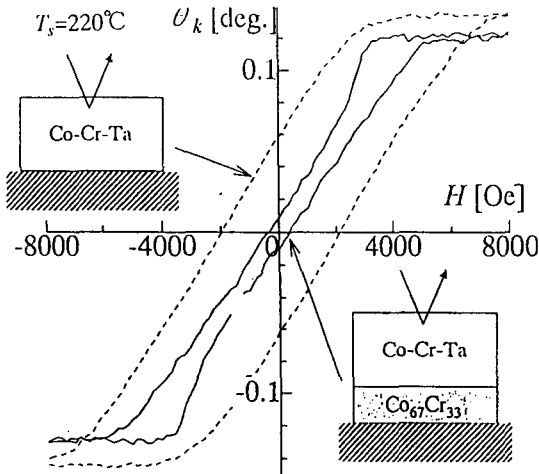


Fig. 3. Kerr hysteresis loops in the Co-Cr-Ta single layer and the Co-Cr-Ta/ $\text{Co}_{67}\text{Cr}_{33}$ double layers

layer. It seems that these layers should be deposited without interval.

On the other hands, $H_{c\perp}$ of the Co-Cr-Ta/ $\text{Co}_{67}\text{Cr}_{33}$ double layer remained at low value about 200 Oe even at T_2 of 220°C as shown in Fig. 2. This value of $H_{c\perp}$ was much lower than the of the Co-Cr-Ta single layer 1500

Table 1. Relationships between coercivity and configuration of specimens deposited under various condition.

	without $\text{Co}_{67}\text{Cr}_{33}$ underlayer $T_s=220^\circ\text{C}$	with $\text{Co}_{67}\text{Cr}_{33}$ underlayer $T_s=220^\circ\text{C}$ $T_{us}=\text{R.T.}$
No N_2 addition	Co-Cr-Ta $H_{c\perp}=1500$ Oe	Co-Cr-Ta $\text{Co}_{67}\text{Cr}_{33}$ $H_{c\perp}=250$ Oe
N_2 addition to initial growth layer	Co-Cr-Ta Co-Cr-Ta:N $H_{c\perp}=1070$ Oe	Co-Cr-Ta Co-Cr-Ta:N $\text{Co}_{67}\text{Cr}_{33}$ $H_{c\perp}=600$ Oe

Oe. Furthermore, the M- H_{\perp} hysteresis loops with a sharp shoulder was observed even at T_2 of 220°C as shown in Fig. 3. These results suggested that the compositional separation into Co-rich and Cr-rich regions was not caused. The drastic decrease of $H_{c\perp}$ seems to be attributed to the effect of $\text{Co}_{67}\text{Cr}_{33}$ underlayer in addition to interval time effect between deposition of the underlayer and the Co-Cr-Ta layer.

Then, the Co-Cr-Ta : N layer was deposited on the $\text{Co}_{67}\text{Cr}_{33}$ underlayer in order to clarify the effect of $\text{Co}_{67}\text{Cr}_{33}$ layer on the Co-Cr-Ta layer. Table 1 lists the relationships between coercivity and configurations of the specimens, deposited under various sputtering condition. $H_{c\perp}$ of the Co-Cr-Ta/ $\text{Co}_{67}\text{Cr}_{33}$ double layer was lower than that of the layer without $\text{Co}_{67}\text{Cr}_{33}$ underlayer regardless of the existence of Co-Cr-Ta : N layer. It should be noted that $H_{c\perp}$ changed from 250 Oe to

600 Oe by insertion of the Co-Cr-Ta : N layer on the $\text{Co}_{67}\text{Cr}_{33}$ underlayers. The addition of N_2 to initial growth layer seems to suppress the effect of $\text{Co}_{67}\text{Cr}_{33}$ underlayer. This result implies that the $\text{Co}_{67}\text{Cr}_{33}$ underlayer has the effect to suppress the increase of the perpendicular coercivity $H_{c\perp}$.

CONCLUSION

The effect of paramagnetic $\text{Co}_{67}\text{Cr}_{33}$ underlayer on the crystallographic and magnetic characteristics of Co-Cr-Ta layer was investigated. It was found that the crystallinity of the Co-Cr-Ta layer was improved by using $\text{Co}_{67}\text{Cr}_{33}$ underlayer. However, the coercivity remained low value of 250 Oe even at

substrate temperature T_s as high as 220°C . The decrease of coercivity seems to be attributed to the effect of the $\text{Co}_{67}\text{Cr}_{33}$ underlayer as well as interval time between deposition of the underlayer and the Co-Cr-Ta layer.

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